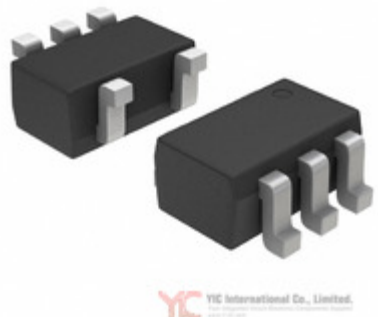








	<h2 style="color: red;">NSB1706DMW5T1G</h2>	
	Hersteller-Teilenummer:	NSB1706DMW5T1G
	Hersteller / Marke:	AMI Semiconductor / ON Semiconductor
	Teil der Beschreibung:	TRANS 2NPN PREBIAS 0.25W SC70
Datenblätter:	 NSB1706DMW5T1G.pdf	
RoHs Status:	Bleifrei / RoHS-konform	
Lagerzustand:	New original, 3049 pcs Stock Available.	
Liefern von:	Hong Kong	
Versandweg:	DHL/Fedex/TNT/UPS/EMS	
<p>Image may be representation. See specs for product details.</p>		

Spezifikationen

Teilenummer	NSB1706DMW5T1G
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	TRANS 2NPN PREBIAS 0.25W SC70
Kategorie	Diskrete Halbleiterprodukte > Transistoren-bipolare
Teilstatus	3049 pcs Stock
Serie	-
Befestigungsart	Surface Mount
Leistung - max	250mW
Verpackung / Gehäuse	5-TSSOP, SC-70-5, SOT-353
Supplier Device-Gehäuse	SC-88A (SC-70-5 / SOT-353)
Transistor-Typ	2 NPN - Pre-Biased (Dual)
Strom - Kollektor (Ic) (max)	100mA
Spannung - Kollektor-Emitter-Durchbruch (max)	50V
VCE Sättigung (Max) @ Ib, Ic	250mV @ 1mA, 10mA
Strom - Collector Cutoff (Max)	500nA
DC Stromgewinn (HFE) (Min) @ Ic, VCE	80 @ 5mA, 10V
Frequenz - Übergang	-
Widerstand - Base (R1) (Ohm)	4.7k
Widerstand - Emitter-Basis (R2) (Ohm)	47k
Verpackung	Tape & Reel (TR)

NSB1706DMW5T1G ist neu im Original, Suche NSB1706DMW5T1G Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie NSB1706DMW5T1G AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage NSB1706DMW5T1G: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>NSB13211DW6T1G AMI Semiconductor / ON Semiconductor TRANS NPN/PNP PREBIAS 0.23W SC88</p>	 <p>NSB4904DW1T1G AMI Semiconductor / ON Semiconductor TRANS NPN/PNP PREBIAS 0.25W SC88</p>	 <p>NSB8AT-E3/81 Electro-Films (EFI) / Vishay DIODE GEN PURP 50V 8A TO263AB</p>	 <p>NSB8AT-E3/45 Electro-Films (EFI) / Vishay DIODE GEN PURP 50V 8A TO263AB</p>
 <p>NSB13ANT3G AMI Semiconductor / ON Semiconductor TVS DIODE 13VWM 21.5VC SMB</p>	 <p>NSB1706DMW5T1 AMI Semiconductor / ON Semiconductor TRANS 2NPN PREBIAS 0.25W SC70</p>	 <p>NSB8AT-E3/45 Vishay / Semiconductor - Diodes Division DIODE GEN PURP 50V 8A TO263AB</p>	 <p>NSB8AT-E3/81 Vishay / Semiconductor - Diodes Division DIODE GEN PURP 50V 8A TO263AB</p>

heiße Teile

Mehr

CGA2B2X8R2A152K050BE	ESD7371P2T5G	ETQP5LR50XFA	D FDC6333C	IR2175SPBF
LDB31942M20C-435	MA4E2200D1-287T	D MGA-43040-TR1G	NSB4904DW1T1G	NSB8JT-E3/31
NSB9435T1	NSB9435T1G	NSBA114EDP6T5G	NSBA114EDXV6T1	NSBA114YDXV6T1
NSBA123JDXV6T1	NSBA123JDXV6T1G	NSBA123JDXV6T5G	NSBA143TDXV6T1G	NSBA144EDP6T5G
NSBC114EDXV6T1	NSBC114EDXV6T1G	NSBC114EPDXV6T1G	NSBC114EPDXV6T5	NSBC114TDXV6T1
NSBC114YDP6T5G	NSBC114YDXV6T1	D NSBC114YDXV6T1G	NSBC114YDXV6T5	NSBC114YPDXV6T1
NSBC115EDXV6T1	D NSBC123JDXV6T1	NSBC123JPDV6T1	NSBC123JPDV6T1G	NSBC124EPDXV6T1
NSBC124EPDXV6T5	NSBC124XPDXV6T1	NSBC143EDXV6T5	NSBC143ZPDV6T1G	NSBC143ZPDV6T5
NSBC144EDXV6T1	NSBC144EDXV6T1G	NSBC144EDXV6T5	D NSBC144EDXV6T5G	NSBC144EPDXV6T1
NSBC144EPDXV6T1G	S-1112B27PN	TLP283-4GB	V48A48H500AL	WI-J60-CW

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